

**B.E/ B.Tech (Full Time) Degree Arrear Examinations, NOV/DEC 2013**  
**Computer Science Engineering Branch**  
**Third Semester**  
**EC294 Electronic Devices & Circuits/ EC9213 Electronic Devices and Circuits**  
**Regulation 2004/2008**

Time:3 Hours

Answer all Questions

Max. Marks 100

**Part A (10X2=20)**

1. Apply voltage division and determine the voltage across  $30\ \Omega$  resistor for the circuit shown in Fig.1.
2. Replace the two current sources shown in Fig.2 by one equivalent current source.

*Handwritten notes:*  
 $\frac{V_{out}}{V_{in}} = \frac{R_2}{R_1 + R_2}$   
 $\frac{V_{out}}{V_{in}} = \frac{20}{20 + 50}$   
 $\frac{V_{out}}{V_{in}} = \frac{20}{70} = \frac{2}{7}$   
 $V_{out} = \frac{2}{7} V_{in}$

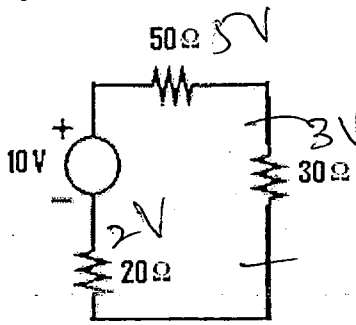


Figure 1.

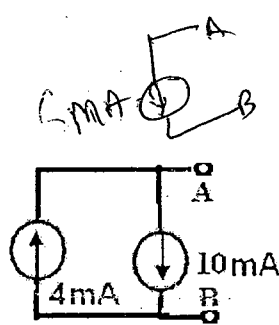


Figure 2.

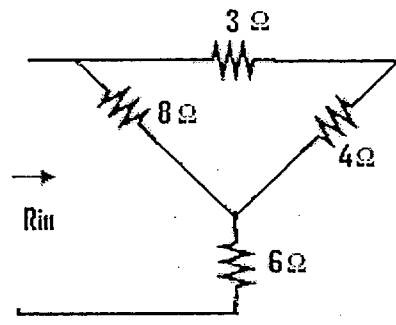


Figure 3.

3. State superposition principle.
4. Determine the equivalent resistance  $R_{in}$  for the circuit shown in Fig.3.
5. What is meant by cut-in voltage for pn junction diode.
6. What is known body effect in MOSFET?
7. What is meant by unity gain bandwidth of an amplifier?
8. Define transconductance of MOSFET.
9. Draw a negative feedback operational amplifier to derive an output voltage  $V_{out} = -6V_{in}$ , here  $V_{in}$  is the input voltage of the operational amplifier.
10. Draw an integrator circuit using opamp.

**PART B (5X16=80)**

11. Using nodal analysis determine the voltage  $V_1$  for the circuit shown in Fig.4 and determine the power dissipated by the  $3K\Omega$  resistor. (16)

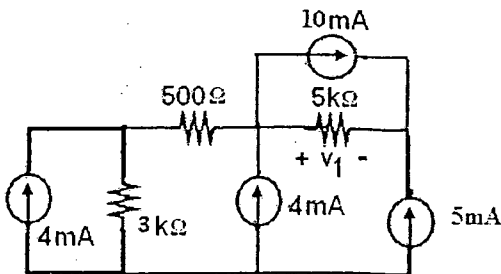


Figure 4.

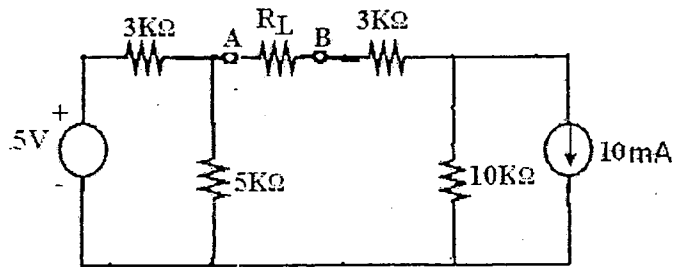


Figure 5.

*Handwritten notes:*  
 $V_1 = 4.875$   
 $P = 1.2$

*Handwritten notes:*  
 9486110735  
 9790494229

- 12 a i. State Thevenin's theorem. (4)  
 ii. Determine the Thevenin equivalent circuit looking into the terminals A, B for the circuit shown in Fig. 5. (12)

(OR)

- 12 b i. State Maximum power transfer theorem. (4)  
 ii. Determine the value of  $R_L$  for the circuit shown in Fig. 6, so that maximum power is transferred. (12)

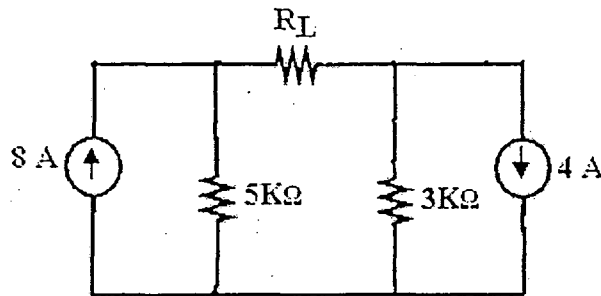


Figure 6.

- 13 a i. Explain the load regulation characteristic of a zener diode. (4)  
 ii. Derive the collector current equation of a BJT in active region and derive its h parameter model. (12)

(OR)

- 13 b i. Derive the current equation of an n-channel MOSFET under various regions of operation condition. (8)  
 ii. Explain the various regions of operation of an n-channel JFET. (8)

- 14 a Explain the principle of operation of a CE amplifier with voltage divider biasing and derive its voltage gain. (16)

(OR)

- 14 b Derive the voltage gain of a CS amplifier by drawing its small signal equivalent model and explain its frequency response. (16)

- 15 a i. Describe the functionality of an opamp used as a first order low pass and high pass filter with appropriate circuit diagram. (8)

- ii. With necessary derivation show that an operational amplifier can be used as a summing and subtractor amplifier. (8)

(OR)

- 15 b i. Derive the gain of an operational amplifier used in inverting and noninverting negative feedback configuration. (8)

- ii. Explain the principle of operation of an inverted R/2R ladder DAC. (8)

